

PNP SILICON TRIPLE DIFFUSED TRANSISTOR
FOR HIGH-SPEED HIGH-VOLTAGE SWITCHING

The 2SA1871 is a transistor developed for high-speed high-voltage switching and is ideal for use in switching elements such as switching regulators and DC/DC converters.

FEATURES

- New package with dimensions in between those of small signal and power signal package
- High voltage
- Fast switching speed
- Complementary transistor with 2SC4942

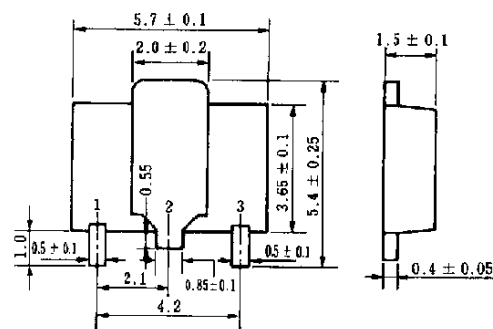
QUALITY GRADES

- Standard
- Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	V_{CBO}		-600	V
Collector to emitter voltage	V_{CEO}		-600	V
Emitter to base voltage	V_{EBO}		-7.0	V
Collector current (DC)	$I_{C(DC)}$		-1.0	A
Collector current (pulse)	$I_{C(pulse)}$	$PW \leq 10 \text{ ms}$, duty cycle $\leq 50 \%$	-2.0	A
Total power dissipation	P_T	7.5 cm ² × 0.7 mm ceramic board used	2.0	W
Junction temperature	T_j		150	°C
Storage temperature	T_{stg}		-55 to +150	°C

PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1: Emitter
- 2: Collector
- 3: Base

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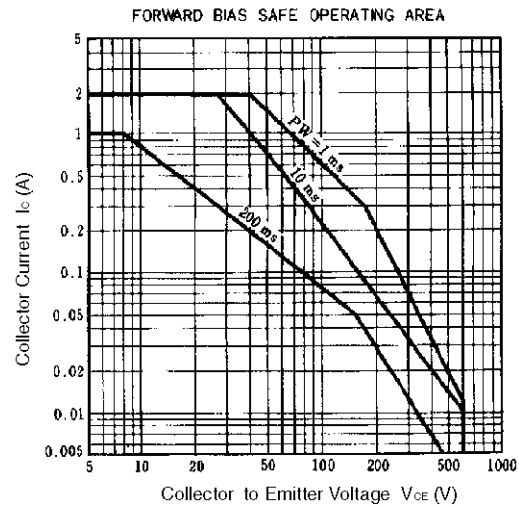
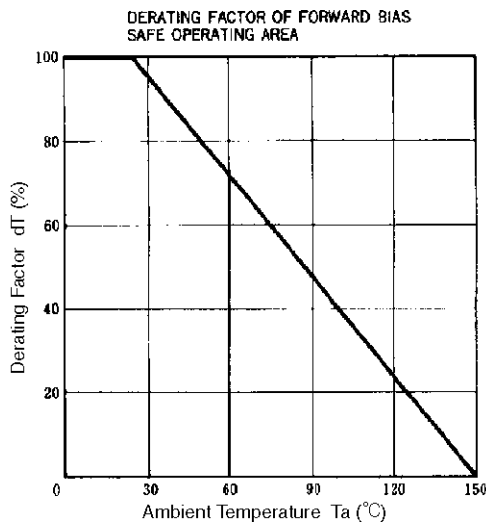
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

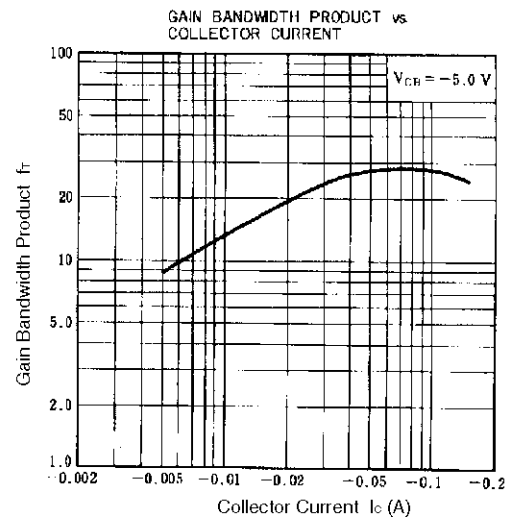
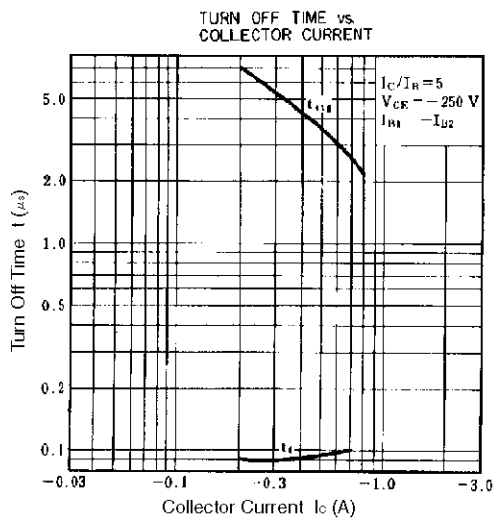
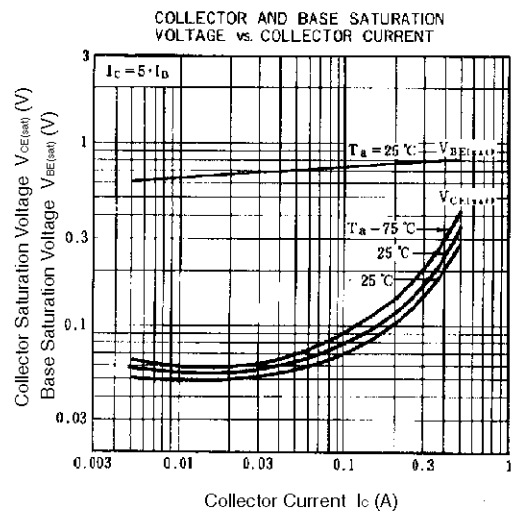
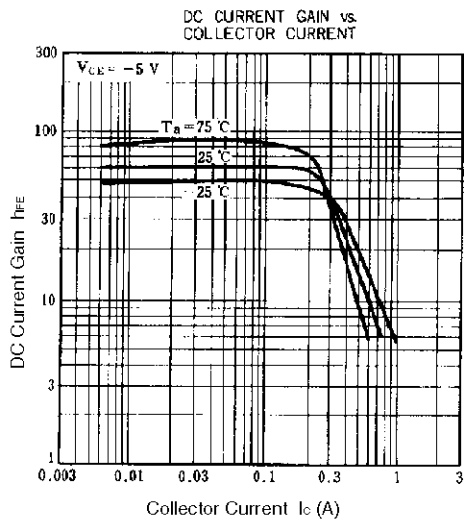
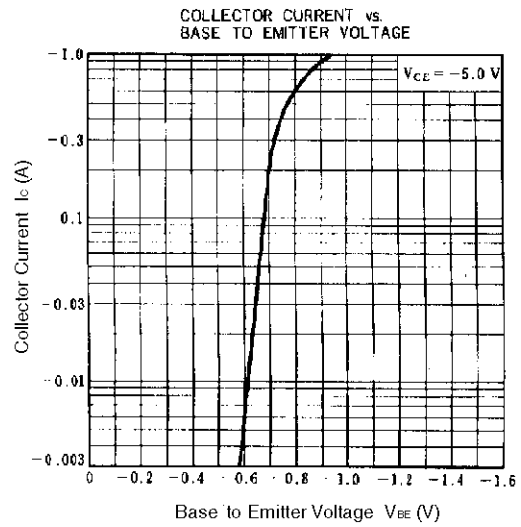
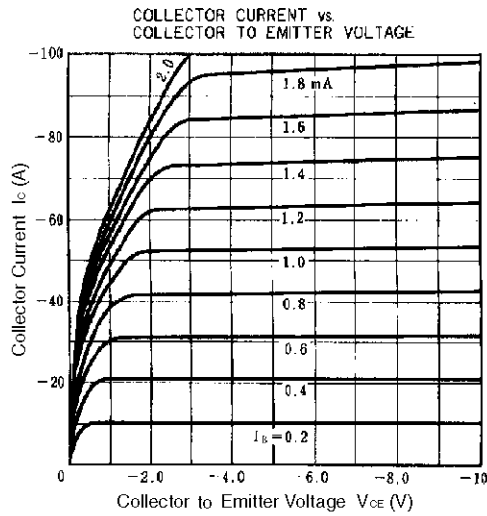
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -600\text{ V}, I_E = 0$			-10	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -7.0\text{ V}, I_C = 0$			-10	μA
DC current gain	h_{FE1}	$V_{CE} = -5.0\text{ V}, I_C = -0.1\text{ A}$	30	60	120	-
DC current gain	h_{FE2}	$V_{CE} = -5.0\text{ V}, I_C = -0.5\text{ A}$	5	20		-
Collector saturation voltage	$V_{CE(sat)}$	$I_C = -300\text{ mA}, I_B = -60\text{ mA}$		-0.3	-1.0	V
Base saturation voltage	$V_{BE(sat)}$	$I_C = -300\text{ mA}, I_B = -60\text{ mA}$		-0.85	-1.2	V
Gain bandwidth product	f_T	$V_{CE} = -10\text{ V}, I_E = 50\text{ mA}$		30		MHz
Output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1.0\text{ MHz}$		40		pF
Turn-on time	t_{on}	$I_C = -0.5\text{ A}, V_{CC} = -250\text{ V}$		0.1	0.5	μs
Storage time	t_{stg}	$I_{B1} = -I_{B2} = -0.1\text{ A},$ $R_L = 500\ \Omega,$		3.5	5.0	μs
Fall time	t_f			0.1	0.5	μs

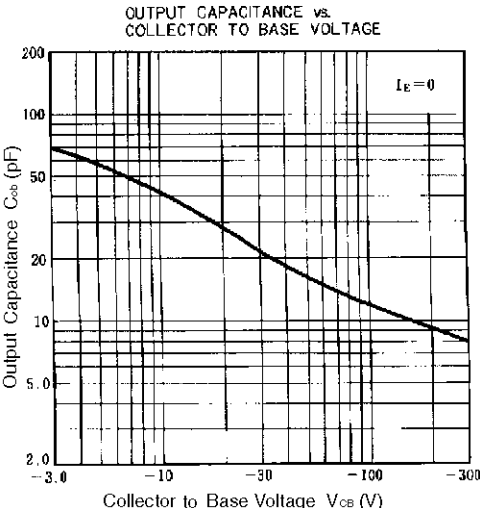
hFE CLASSIFICATION

Marking	GA1	GA2	GA3
h_{FE1}	30 to 60	40 to 80	60 to 120

TYPICAL CHARACTERISTICS (Ta = 25°C)







[MEMO]

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